NSN 5962-01-370-8093

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View Online at https://aerobasegroup.com/nsn/5962-01-370-8093

Body Length: 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 1.1 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 5895-01-305-8863 recorder, signal data **Features Provided:** Bipolar and programmed and high impedance and w/clock and bidirectional and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Current Rating Per Characteristic:** 90.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Registered and-or-gate array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 12.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, high to low level output and 50.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Pal

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

Test Data Document:

20 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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